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Index

IEE Proceedings
Circuits, Devices and Systems
Vol. 141, 1994

Author index

A

Abdel-Raheem, E., El-Guibaly, F., and Antoniou, A. Systolic implementation of FIR decimators and interpolators p489
Abou-Fakher, Y., Peyton, A.J., and Wilson, B. see Peyton, A.J.
Agius, B., Stroh, R.J., Plais, F., Kretz, T., Legagneux, P., Huet, O., Magis, M., Pribat, D., Jiang, N., and Hugon, M.C. see Stroh, R.J.
Al-Ghamdi, S., and El-Hennawy, A. see El-Hennawy, A.
Algani, C., Zuberek, W.M., Konczykowska, A., Wang, H., and Dangla, J. see Zuberek, W.M.
Ananda Mohan, P.V., and Prasanna, B.S. see Prasanna, B.S.
Antoniou, A., Abdel-Raheem, E., and El-Guibaly, F. see Abdel-Raheem, E.
Armstrong, B.M., Wu, Y., Montgomery, J.H., Refsum, A., Mitchell, S.J.N., and Gamble, H.S. see Wu, Y.
Attikiouzel, Y., Kuczborski, W., and Crebbin, G. see Kuczborski, W.
Ayres, J.R., Brotherton, S.D., Clarence, I.R., and Dobson, P.J. Photocurrents in poly-Si TFTs p27
Ayres, J.R., and Young, N.D. Hot carrier effects in devices and circuits formed from poly-Si p38
Aziz, S.M., and Waller, W.A.J. Testing differential split-level CMOS circuits p451

B

Bailey, N.J., Nooralahiyan, A.Y., and Hoyle, B.S. see Nooralahiyan, A.Y.
Baker, K.R., Brown, A.D., and Currie, A.J. Optimisation efficiency in behavioural synthesis p399
Batarseh, I., and Siri, K. LLC-type series resonant convertor with PWM control p73
Beck, M.S., Xie, C.G., Huang, S.M., Lenn, C.P., and Stott, A.L. see Xie, C.G.
Beck, M.S., Yang, W.Q., and Stott, A.L. see Yang, W.Q.
Bermudez, J.C.M., Schneider, M.C., and Galup-Montoro, C. see Schneider, M.C.
Bernstein, R.W., and Heide, C.F. Optimisation of signal phase split in vector modulator phase shifters p207
Bhaskar, D.R., and Senani, R. see Senani, R.
Bhattacharya, P.K., and Nandakumar, R.P. Effect of X-ray irradiation on submicrometre channel length MOSFETs p193
Board, K., Hu, Z.R., Mawby, P.A., Towers, M.S., and Zeng, J. see Hu, Z.R.
Board, K., Mawby, P.A., Hu, Z.-R., Towers, M.S., and Evans, M.J. see Mawby, P.A.
Bonnaud, O., Sarret, M., Liba, A., Le Bihan, F., Fortin, B., Pichon, L., and Raoult, F. see Sarret, M.
Bowron, P., and Mezher, K.A. Noise analysis of second-order analogue active filters p350
Brinson, M.E., and Faulkner, D.J. Modular SPICE macromodel for operational amplifiers p417
Brotherton, S.D., Ayres, J.R., Clarence, I.R., and Dobson, P.J. see Ayres, J.R.
Brown, A.D., Baker, K.R., and Currie, A.J. see Baker, K.R.
Brown, A.D., Nichols, K.G., Kazmierski, T.J., and Zwolinski, M. see Nichols, K.G.
Bulll, D.R., and Wacey, G. Bit-serial digital filter architecture using RAM-based delay operators p371
Bushehri, E., and Janković, N.D. see Janković, N.D.

C

Carlosena, A., Celma, S., and Martínez, P.A. see Celma, S.
Celma, S., Martínez, P.A., and Carlosena, A. Approach to the synthesis of canonic RC-active oscillators using CCII p493
Chan, P.K., and Wilson, G. see Wilson, G.
Charlot, J.-J., and Vladimirescu, A. see Vladimirescu, A.
Chen, W.-K., Lu, A., Wu, X., and Zhuang, W. see Lu, A.
Clarence, I.R., Ayres, J.R., Brotherton, S.D., and Dobson, P.J. see Ayres, J.R.
Clark, M.G. Current status and future prospects of poly-Si devices p3
Commerçon, J.C., and Guivarch, M. Current transistor–transistor–inductor oscillator p498
Conti, M., Orcioni, S., and Turchetti, C. Parametric yield optimisation of MOS VLSI circuits based on simulated annealing and its parallel implementation p387
Craven, M.P., Curtis, K.M., and Hayes-Gill, B.R. Consideration of multiplexing in neural network hardware p237
Crebbin, G., Kuczborski, W., and Attikiouzel, Y. see Kuczborski, W.
Currie, A.J., Baker, K.R., and Brown, A.D. see Baker, K.R.
Curtis, K.M., Craven, M.P., and Hayes-Gill, B.R. see Craven, M.P.

D

Daneshgaran, F., and Yao, K. Efficient parallel pipelinable VLSI architecture for finding the maximum binary number p527
Dangla, J., Zuberek, W.M., Konczykowska, A., Algani, C., and Wang, H. see Zuberek, W.M.
Davies, J.F., Dyer, T.E., Marshall, J.M., Pickin, W., and Hepburn, A.R. see Dyer, T.E.
Dempster, A.G., and Macleod, M.D. Constant integer multiplication using minimum adders p407
Deng, X., Hanyu, T., and Kameyama, M. Design and evaluation of a current-mode multiple-valued PLA based on a resonant tunnelling transistor model p445
Dias, J.A.S., and Martins, M.M. see Martins, M.M.
Dobson, P.J., Ayres, J.R., Brotherton, S.D., and Clarence, I.R. see Ayres, J.R.
Durham, A.M., and Redman-White, W. see Redman-White, W.
Dyer, T.E., Marshall, J.M., Pickin, W., Hepburn, A.R., and Davies, J.F. Optoelectronic and structural properties of polysilicon produced by excimer laser and furnace crystallisation of hydrogenated amorphous silicon (a-Si:H) p15

E

Edwards, M.J. NMOS and CMOS polysilicon drive circuits for liquid crystal displays p50
El-Guibaly, F., Abdel-Raheem, E., and Antoniou, A. see Abdel-Raheem, E.
El-Hennawy, A., and Al-Ghamdi, S. Performance improvement of MOSFET lasers by using trapezoidal gate MOSFETs p69
El-Masry, E.I., and Yang, H.K. see Yang, H.K.
El-Rabaie, N., El-Rabaie, S., and Ibrahim, S.A. see El-Rabaie, S.
El-Rabaie, S., Ibrahim, S.A., and El-Rabaie, N. Applying the controlled aliasing technique for fast prediction of the output response of nonlinear circuits driven by composite signals p65
Erickson, R.W., and Singer, S. see Singer, S.
Evans, M.J., Mawby, P.A., Hu, Z.-R., Towers, M.S., and Board, K. see Mawby, P.A.

F

Fabre, A. New formulations to describe translinear mixed cells accurately p167
Faulkner, D.J., and Brinson, M.E. see Brinson, M.E.
Feng, S., and Seitzer, D. Improved passive model for transient prediction of GaAs E/D MESFET analogue switches p105
Fidan, M., Güneş, F., and Güneş, M. see Güneş, F.
Fidler, J.K., Teng, J., and Zheng, L. see Teng, J.
Fluxman, S., and Reita, C. see Reita, C.
Fluxman, S.M. Design and performance of digital polysilicon thin-film-transistor circuits on glass p56
Fortin, B., Sarret, M., Liba, A., Bonnaud, O., Le Bihan, F., Pichon, L., and Raoult, F. see Sarret, M.
Fortunato, G., Pecora, A., Tallarida, G., Mariucci, L., Reita, C., and Migliorato, P. see Pecora, A.
Fortunato, G., Quinn, M., Migliorato, P., Reita, C., Pecora, A., and Tallarida, G. see Quinn, M.

G

Galup-Montoro, C., Schneider, M.C., and Bermudez, J.C.M. see Schneider, M.C.
Gamble, H.S., Wu, Y., Montgomery, J.H., Refsum, A., Mitchell, S.J.N., and Armstrong, B.M. see Wu, Y.
Gatti, U., Maloberti, F., Palmisano, G., and Torelli, G. CMOS triode-transistor transconductor for high-frequency continuous-time filters p462
Goel, A.K., and Mathur, M.K. Modelling of propagation delays in the bilevel crossing interconnections on the GaAs-based integrated circuits p185
Goldberg, J.M., and Sandler, M.B. New high accuracy pulse width modulation based digital-to-analogue convertor/power amplifier p315
Greer, N.P.J., Henderson, R.K., Ping, L., and Sewell, J.I. Matrix methods for the design of transconductor ladder filters p89
Güneş, F., Güneş, M., and Fidan, M. Performance characterisation of a microwave transistor p337
Güneş, M., Güneş, F., and Fidan, M. see Güneş, F.
Guivarch, M., and Commerçon, J.C. see Commerçon, J.C.

H

Hanyu, T., Deng, X., and Kameyama, M. see Deng, X.
Hawksford, M.O.J. Differential-current derived feedback in error-correcting audio amplifier applications p227
Hayes-Gill, B.R., Craven, M.P., and Curtis, K.M. see Craven, M.P.
He, J. Detection of weak Doppler signal in a strong carrier: an equivalent high-Q band-elimination filter p377
Heide, C.F., and Bernstein, R.W. see Bernstein, R.W.
Henderson, R.K., Greer, N.P.J., Ping, L., and Sewell, J.I. see Greer, N.P.J.
Hepburn, A.R., Dyer, T.E., Marshall, J.M., Pickin, W., and Davies, J.F. see Dyer, T.E.
Ho, Y.-K., Yang, W.-P., Ker, J.-S., and Kuo, Y.-H. see Yang, W.-P.
Hoile, G.A., and Reader, H.C. Computer-aided design of an RF MOSFET power amplifier p433
Hoyle, B.S., Nooralahiyan, A.Y., and Bailey, N.J. see Nooralahiyan, A.Y.
Hu, Z.-R., Mawby, P.A., Towers, M.S., Evans, M.J., and Board, K. see Mawby, P.A.
Hu, Z.R., Mawby, P.A., Towers, M.S., Board, K., and Zeng, J. Degradation in on-state characteristics of IGBTs through self-heating p439
Huang, C.I., Liou, J.J., and Liou, L.L. see Liou, J.J.
Huang, S.M., Xie, C.G., Lenn, C.P., Stott, A.L., and Beck, M.S. see Xie, C.G.
Huet, O., Stroh, R.J., Plais, F., Kretz, T., Legagneux, P., Magis, M., Pribat, D., Jiang, N., Hugon, M.C., and Agius, B. see Stroh, R.J.
Hugon, M.C., Stroh, R.J., Plais, F., Kretz, T., Legagneux, P., Huet, O., Magis, M., Pribat, D., Jiang, N., and Agius, B. see Stroh, R.J.

I

Ibrahim, S.A., El-Rabaie, S., and El-Rabaie, N. see El-Rabaie, S.
Ishibashi, Y. Active *RC* filter based on simulation of dissipative *LC* filters p101
Ishibashi, Y., and Urakawa, H. Leap-frog circuit compensating influence of GB product and second pole of operational amplifier p203
Itakura, T. Effects of the sampling pulse width on the frequency characteristics of a sample-and-hold circuit p328

J

Janković, N.D., and Bushehri, E. Theoretical and experimental evaluation of high-voltage CMOS inverters p162

Jeppson, K.O., and Karlsson, P.R. see Karlsson, P.R.
Jiang, M.-C., and Pan, C.-T. Fast peak detector for variable frequency three-phase sinusoidal signals p151
Jiang, N., Stroh, R.J., Plais, F., Kretz, T., Legagneux, P., Huet, O., Magis, M., Pribat, D., Hugon, M.C., and Agius, B. see Stroh, R.J.

K

Kameyama, M., Deng, X., and Hanyu, T. see Deng, X.
Kanellakis, A. New stability results for 2-D discrete systems based on the Fornasini–Marchesini state space model p427
Karlsson, P.R., and Jeppson, K.O. Analytical extraction method for submicron MOS transistor model parameters in the linear region p457
Kazmierski, T.J., Nichols, K.G., Zwolinski, M., and Brown, A.D. see Nichols, K.G.
Kenington, P.B., and Parsons, K.J. see Parsons, K.J.
Ker, J.-S., Yang, W.-P., Kuo, Y.-H., and Ho, Y.-K. see Yang, W.-P.
Kleihorst, E. Extended harmonic balance method p275
Konczykowska, A., Zuberek, W.M., Algani, C., Wang, H., and Dangla, J. see Zuberek, W.M.
Kretz, T., Stroh, R.J., Plais, F., Legagneux, P., Huet, O., Magis, M., Pribat, D., Jiang, N., Hugon, M.C., and Agius, B. see Stroh, R.J.
Kuczborski, W., Attikiouzel, Y., and Crebbin, G. Decomposition of logic networks with emphasis on signed digit arithmetic systems p307
Kuo, Y.-H., Yang, W.-P., Ker, J.-S., and Ho, Y.-K. see Yang, W.-P.

L

Le Bihan, F., Sarret, M., Liba, A., Bonnaud, O., Fortin, B., Pichon, L., and Raoult, F. see Sarret, M.
Legagneux, P., Stroh, R.J., Plais, F., Kretz, T., Huet, O., Magis, M., Pribat, D., Jiang, N., Hugon, M.C., and Agius, B. see Stroh, R.J.
Lenn, C.P., Xie, C.G., Huang, S.M., Stott, A.L., and Beck, M.S. see Xie, C.G.
Li, C.-H., and Yam, Y.-O. Maximum frequency and optimum performance of class E power amplifiers p174
Liba, A., Sarret, M., Bonnaud, O., Le Bihan, F., Fortin, B., Pichon, L., and Raoult, F. see Sarret, M.
Liou, J.J., Liou, L.L., and Huang, C.I. Analytical model for the AlGaAs/GaAs multiemitter finger HBT including self-heating and thermal coupling effects p469
Liou, L.L., Liou, J.J., and Huang, C.I. see Liou, J.J.
Litovski, V.B., and Milenković, S.L. see Milenković, S.L.
Lu, A., Wu, X., Zhuang, W., and Chen, W.-K. New global routing subsystem for CMOS gate arrays p421

M

Macleod, M.D., and Dempster, A.G. see Dempster, A.G.
Magis, M., Stroh, R.J., Plais, F., Kretz, T., Legagneux, P., Huet, O., Pribat, D., Jiang, N., Hugon, M.C., and Agius, B. see Stroh, R.J.
Maloberti, F., Gatti, U., Palmisano, G., and Torelli, G. see Gatti, U.
Mariucci, L., Pecora, A., Tallarida, G., Fortunato, G., Reita, C., and Migliorato, P. see Pecora, A.
Marshall, J.M., Dyer, T.E., Pickin, W., Hepburn, A.R., and Davies, J.F. see Dyer, T.E.
Martinez, P.A., Celma, S., and Carlosena, A. see Celma, S.
Martinelli, G., Prina Ricotti, L., and Ragazzini, S. Distributed arithmetic perceptron p382
Martins, M.M., and Dias, J.A.S. CMOS shunt regulator with bandgap reference for automotive environment p157
Mathur, M.K., and Goel, A.K. see Goel, A.K.
Mawby, P.A., Hu, Z.-R., Towers, M.S., Evans, M.J., and Board, K. Recombination and Joule heating effects in GTO thyristors with spatially varying lifetimes p292
Mawby, P.A., Hu, Z.R., Towers, M.S., Board, K., and Zeng, J. see Hu, Z.R.
Mezher, K.A., and Bowron, P. see Bowron, P.
Migliorato, P., Pecora, A., Tallarida, G., Fortunato, G., Mariucci, L., and Reita, C. see Pecora, A.
Migliorato, P., Quinn, M., Reita, C., Pecora, A., Tallarida, G., and Fortunato, G. see Quinn, M.
Milenković, S.L., and Litovski, V.B. New analytical procedure for automatic cell placement in gate-arrays p476
Mitchell, S.J.N., Wu, Y., Montgomery, J.H., Refsum, A., Armstrong, B.M., and Gamble, H.S. see Wu, Y.
Montgomery, J.H., Wu, Y., Refsum, A., Mitchell, S.J.N., Armstrong, B.M., and Gamble, H.S. see Wu, Y.
Murthy, K.V.V., Pai, K.R., and Ramachandran, V. see Pai, K.R.

N

Nandakumar, R.P., and Bhattacharya, P.K. see Bhattacharya, P.K.
Napieralski, A., and Turowski, M. see Turowski, M.
Nichols, K.G., Kazmierski, T.J., Zwolinski, M., and Brown, A.D. Overview of SPICE-like circuit simulation algorithms p242
Nooralahiyan, A.Y., Hoyle, B.S., and Bailey, N.J. Neural network for pattern association in electrical capacitance tomography p517

O

Orcioni, S., Conti, M., and Turchetti, C. see Conti, M.

P

Pai, K.R., Murthy, K.V.V., and Ramachandran, V. Pole-parameter analysis: a novel approach for the design of filters p121
Palmisano, G., Gatti, U., Maloberti, F., and Torelli, G. see Gatti, U.
Pan, C.-T., and Jiang, M.-C. see Jiang, M.-C.
Parker, A.E. Implementing high-order continuity and rate dependence in SPICE models p251
Parsons, K.J., and Kenington, P.B. Effect of delay mismatch on a feedforward amplifier p140
Pecora, A., Quinn, M., Migliorato, P., Reita, C., Tallarida, G., and Fortunato, G. see Quinn, M.
Pecora, A., Tallarida, G., Fortunato, G., Mariucci, L., Reita, C., and Migliorato, P. Hot-hole-induced degradation in polycrystalline silicon thin-film transistors: experimental and theoretical analysis p33
Peyton, A.J., Abou-Fakher, Y., and Wilson, B. Analysis of a composite amplifier technique for optimum noise performance p210
Pichon, L., Sarret, M., Liba, A., Bonnaud, O., Le Bihan, F., Fortin, B., and Raoult, F. see Sarret, M.
Pickin, W., Dyer, T.E., Marshall, J.M., Hepburn, A.R., and Davies, J.F. see Dyer, T.E.
Ping, L., Greer, N.P.J., Henderson, R.K., and Sewell, J.I. see Greer, N.P.J.
Plais, F., Stroh, R.J., Kretz, T., Legagneux, P., Huet, O., Magis, M., Pribat, D., Jiang, N., Hugon, M.C., and Agius, B. see Stroh, R.J.
Pourbigharaz, F., and Yassine, H.M. Simple binary to residue transformation with respect to $2^m + 1$ moduli p522
Prakash, V.P., and Prasad, V.C. see Prasad, V.C.
Prasad, V.C., and Prakash, V.P. Uniqueness of solutions of networks with two terminal piecewise linear resistors p369
Prasanna, B.S., and Ananda Mohan, P.V. Fast VLSI architectures using nonredundant multibit recoding for computing $A^Y \bmod N$ p345
Pribat, D., Stroh, R.J., Plais, F., Kretz, T., Legagneux, P., Huet, O., Magis, M., Jiang, N., Hugon, M.C., and Agius, B. see Stroh, R.J.
Prina Ricotti, L., Martinelli, G., and Ragazzini, S. see Martinelli, G.

Q

Quinn, M., Migliorato, P., Reita, C., Pecora, A., Tallarida, G., and Fortunato, G. High-field effects in polysilicon thin-film transistors p45

R

Ragazzini, S., Martinelli, G., and Prina Ricotti, L. see Martinelli, G.
Ramachandran, V., Pai, K.R., and Murthy, K.V.V. see Pai, K.R.
Raoult, F., Sarret, M., Liba, A., Bonnaud, O., Le Bihan, F., Fortin, B., and Pichon, L. see Sarret, M.
Reader, H.C., and Hoile, G.A. see Hoile, G.A.
Redman-White, W., and Durham, A.M. Integrated fourth-order $\Sigma\Delta$ convertor with stable self-tuning continuous-time noise shaper p145
Refsum, A., Wu, Y., Montgomery, J.H., Mitchell, S.J.N., Armstrong, B.M., and Gamble, H.S. see Wu, Y.
Reita, C., Pecora, A., Tallarida, G., Fortunato, G., Mariucci, L., and Migliorato, P. see Pecora, A.
Reita, C., Quinn, M., Migliorato, P., Pecora, A., Tallarida, G., and Fortunato, G. see Quinn, M.
Reita, C., and Fluxman, S. Design and operation of poly-Si analogue circuits p60

S

Sandler, M.B., and Goldberg, J.M. see Goldberg, J.M.
Sarmiento Reyes, A. Efficient partitioning-based method to determine the upper bound on the number of operating points in transistor circuits p258
Sarret, M., Liba, A., Bonnaud, O., Le Bihan, F., Fortin, B., Pichon, L., and Raoult, F. In-*situ* phosphorous-doped VLPCVD polysilicon layers for polysilicon thin-film transistors p19
Schneider, M.C., Galup-Montoro, C., and Bermudez, J.C.M. Explicit formula for harmonic distortion in SC filters with weakly nonlinear capacitors p505
Seitzer, D., and Feng, S. see Feng, S.
Senani, R., and Bhaskar, D.R. Versatile voltage-controlled impedance configuration p414
Sewell, J.I., Greer, N.P.J., Henderson, R.K., and Ping, L. see Greer, N.P.J.
Singer, S., and Erickson, R.W. Power-source element and its properties p220
Siri, K., and Batarseh, I. see Batarseh, I.
Song, X., and Tan, X. see Tan, X.
Stott, A.L., Xie, C.G., Huang, S.M., Lenn, C.P., and Beck, M.S. see Xie, C.G.
Stott, A.L., Yang, W.Q., and Beck, M.S. see Yang, W.Q.
Stouraitis, T. Analogue- and binary-to-residue conversion schemes p135
Stroh, R.J., Plais, F., Kretz, T., Legagneux, P., Huet, O., Magis, M., Pribat, D., Jiang, N., Hugon, M.C., and Agius, B. Low-temperature ($\leqslant 600°C$) polysilicon thin-film transistors p9

T

Tallarida, G., Pecora, A., Fortunato, G., Mariucci, L., Reita, C., and Migliorato, P. see Pecora, A.
Tallarida, G., Quinn, M., Migliorato, P., Reita, C., Pecora, A., and Fortunato, G. see Quinn, M.
Tan, X., and Song, X. Improvement on the diagonal routing model p535
Teng, J., Fidler, J.K., and Zheng, L. Pole placement algorithm for equiripple bandstop filter design p325
Torelli, G., Gatti, U., Maloberti, F., and Palmisano, G. see Gatti, U.
Towers, M.S., Hu, Z.R., Mawby, P.A., Board, K., and Zeng, J. see Hu, Z.R.
Towers, M.S., Mawby, P.A., Hu, Z.-R., Evans, M.J., and Board, K. see Mawby, P.A.
Turchetti, C., Conti, M., and Orcioni, S. see Conti, M.
Turowski, M., and Napieralski, A. Two-dimensional analysis of GTO switching under the influence of external circuit p483

U

Urakawa, H., and Ishibashi, Y. see Ishibashi, Y.

V

Vladimirescu, A., and Charlot, J.-J. MOS analogue circuit simulation with SPICE p265

W

Wacey, G., and Bulll, D.R. see Bulll, D.R.
Waller, W.A.J., and Aziz, S.M. see Aziz, S.M.
Wang, H., Zuberek, W.M., Konczykowska, A., Algani, C., and Dangla, J. see Zuberek, W.M.
Whight, K.R. Large signal periodic time-domain circuit simulation p285
Wilkinson, R.H. High-fidelity FIR filters based on central-difference operators p111
Wilson, B., Peyton, A.J., and Abou-Fakher, Y. see Peyton, A.J.
Wilson, G., and Chan, P.K. Analysis of nonlinearities in MOS floating resistor networks p82
Wu, X., Lu, A., Zhuang, W., and Chen, W.-K. see Lu, A.
Wu, Y., Montgomery, J.H., Refsum, A., Mitchell, S.J.N., Armstrong, B.M., and Gamble, H.S. Large-area shower implanter for thin-film transistors p23

X

Xie, C.G., Huang, S.M., Lenn, C.P., Stott, A.L., and Beck, M.S. Experimental evaluation of capacitance tomographic flow imaging systems using physical models p357

Y

Yam, Y.-O., and Li, C.-H. see Li, C.-H.
Yang, H.K., and El-Masry, E.I. Clock feedthrough analysis and cancellation in current sample/hold circuits p510

Yang, W.-P., Ker, J.-S., Kuo, Y.-H., and Ho, Y.-K. Two-level partitioning algorithm with stable performance p197
Yang, W.Q., Stott, A.L., and Beck, M.S. High frequency and high resolution capacitance measuring circuit for process tomography p215
Yao, K., and Daneshgaran, F. see Daneshgaran, F.
Yassine, H.M., and Pourbigharaz, F. see Pourbigharaz, F.
Young, N.D., and Ayres, J.R. see Ayres, J.R.
Yuan, J.S. Base current reversal in bipolar transistors and circuits: a review and update p299

Z

Zeng, J., Hu, Z.R., Mawby, P.A., Towers, M.S., and Board, K. see Hu, Z.R.
Zheng, L., Teng, J., and Fidler, J.K. see Teng, J.
Zhuang, W., Lu, A., Wu, X., and Chen, W.-K. see Lu, A.
Zuberek, W.M., Konczykowska, A., Algani, C., Wang, H., and Dangla, J. Simulation-based parameter extraction, its implementation and some applications p129
Zwolinski, M., Nichols, K.G., Kazmierski, T.J., and Brown, A.D. see Nichols, K.G.

Subject index

AMPLIFIERS

Analysis of a composite amplifier technique for optimum noise performance. A.J. Peyton, Y. Abou-Fakher and B. Wilson p210
Effect of delay mismatch on a feedforward amplifier. K.J. Parsons and P.B. Kenington p140
Leap-frog circuit compensating influence of GB product and second pole of operational amplifier. Y. Ishibashi and H. Urakawa p203
Maximum frequency and optimum performance of class E power amplifiers. C.-H. Li and Y.-O. Yam p174
Modular SPICE macromodel for operational amplifiers. M.E. Brinson and D.J. Faulkner p417

ANALOGUE FILTERS

Noise analysis of second-order analogue active filters. P. Bowron and K.A. Mezher p350

ANALOGUE-DIGITAL CONVERSION

Integrated fourth-order ΣΔ convertor with stable self-tuning continuous-time noise shaper. W. Redman-White and A.M. Durham p145
New high accuracy pulse width modulation based digital-to-analogue convertor/power amplifier. J.M. Goldberg and M.B. Sandler p315

ANTENNAS (ARRAYS)

Optimisation of signal phase split in vector modulator phase shifters. R.W. Bernstein and C.F. Heide p207

ARRAY PROCESSING

New global routing subsystem for CMOS gate arrays. A. Lu, X. Wu, W. Zhuang and W.-K. Chen p421

CIRCUIT THEORY AND DESIGN

Applying the controlled aliasing technique for fast prediction of the output response of nonlinear circuits driven by composite signals. S. El-Rabaie, S.A. Ibrahim and N. El-Rabaie p65
Bit-serial digital filter architecture using RAM-based delay operators. D.R. Bulll and G. Wacey p371
CMOS shunt regulator with bandgap reference for automotive environment. M.M. Martins and J.A.S. Dias p157
Detection of weak Doppler signal in a strong carrier: an equivalent high-Q band-elimination filter. J. He p377
Effects of the sampling pulse width on the frequency characteristics of a sample-and-hold circuit. T. Itakura p328
Efficient partitioning-based method to determine the upper bound on the number of operating points in transistor circuits. A. Sarmiento Reyes p258
Extended harmonic balance method. E. Kleihorst p275
High frequency and high resolution capacitance measuring circuit for process tomography. W.Q. Yang, A.L. Stott and M.S. Beck p215
LLC-type series resonant convertor with PWM control. I. Batarseh and K. Siri p73
MOS analogue circuit simulation with SPICE. A. Vladimirescu and J.-J. Charlot p265
Modelling of propagation delays in the bilevel crossing interconnections on the GaAs-based integrated circuits. A.K. Goel and M.K. Mathur p185
Optimisation efficiency in behavioural synthesis. K.R. Baker, A.D. Brown and A.J. Currie p399
Parametric yield optimisation of MOS VLSI circuits based on simulated annealing and its parallel implementation. M. Conti, S. Orcioni and C. Turchetti p387
Power-source element and its properties. S. Singer and R.W. Erickson p220
Simulation-based parameter extraction, its implementation and some applications. W.M. Zuberek, A. Konczykowska, C. Algani, H. Wang and J. Dangla p129

COMMUNICATION SYSTEMS THEORY

Implementing high-order continuity and rate dependence in SPICE models. A.E. Parker p251

COMPUTER APPLICATIONS

Distributed arithmetic perceptron. G. Martinelli, L. Prina Ricotti and S. Ragazzini p382

CONVERTORS

Analogue- and binary-to-residue conversion schemes. T. Stouraitis p135
LLC-type series resonant convertor with PWM control. I. Batarseh and K. Siri p73

DESIGN

Optimisation efficiency in behavioural synthesis. K.R. Baker, A.D. Brown and A.J. Currie p399

DETECTION

Fast peak detector for variable frequency three-phase sinusoidal signals. M.-C. Jiang and C.-T. Pan p151

DIGITAL CIRCUITS

Theoretical and experimental evaluation of high-voltage CMOS inverters. N.D. Janković and E. Bushehri p162

FEEDBACK

Differential-current derived feedback in error-correcting audio amplifier applications. M.O.J. Hawksford p227

FILTERS AND FILTERING

Active *RC* filter based on simulation of dissipative *LC* filters. Y. Ishibashi p101
Bit-serial digital filter architecture using RAM-based delay operators. D.R. Bulll and G. Wacey p371
CMOS triode-transistor transconductor for high-frequency continuous-time filters. U. Gatti, F. Maloberti, G. Palmisano and G. Torelli p462
Detection of weak Doppler signal in a strong carrier: an equivalent high-Q band-elimination filter. J. He p377
Explicit formula for harmonic distortion in SC filters with weakly nonlinear capacitors. M.C. Schneider, C. Galup-Montoro and J.C.M. Bermudez p505
High-fidelity FIR filters based on central-difference operators. R.H. Wilkinson p111
Leap-frog circuit compensating influence of GB product and second pole of operational amplifier. Y. Ishibashi and H. Urakawa p203
Matrix methods for the design of transconductor ladder filters. N.P.J. Greer, R.K. Henderson, L. Ping and J.I. Sewell p89
Noise analysis of second-order analogue active filters. P. Bowron and K.A. Mezher p350
Pole-parameter analysis: a novel approach for the design of filters. K.R. Pai, K.V.V. Murthy and V. Ramachandran p121

IMAGE PROCESSING

Experimental evaluation of capacitance tomographic flow imaging systems using physical models. C.G. Xie, S.M. Huang, C.P. Lenn, A.L. Stott and M.S. Beck p357

INTEGRATED CIRCUITS

Design and evaluation of a current-mode multiple-valued PLA based on a resonant tunnelling transistor model. X. Deng, T. Hanyu and M. Kameyama p445
Parametric yield optimisation of MOS VLSI circuits based on simulated annealing and its parallel implementation. M. Conti, S. Orcioni and C. Turchetti p387
Performance improvement of MOSFET lasers by using trapezoidal gate MOSFETs. A. El-Hennawy and S. Al-Ghamdi p69
Testing differential split-level CMOS circuits. S.M. Aziz and W.A.J. Waller p451

LOAD AND VOLTAGE REGULATION

Versatile voltage-controlled impedance configuration. R. Senani and D.R. Bhaskar p414

LOGIC

Decomposition of logic networks with emphasis on signed digit arithmetic systems. W. Kuczborski, Y. Attikiouzel and G. Crebbin p307

LONG-TERM PLANNING

New formulations to describe translinear mixed cells accurately. A. Fabre p167

MATHEMATICAL TECHNIQUES

Constant integer multiplication using minimum adders. A.G. Dempster and M.D. Macleod p407
Distributed arithmetic perceptron. G. Martinelli, L. Prina Ricotti and S. Ragazzini p382
Large signal periodic time-domain circuit simulation. K.R. Whight p285
New analytical procedure for automatic cell placement in gate-arrays. S.L. Milenković and V.B. Litovski p476
New global routing subsystem for CMOS gate arrays. A. Lu, X. Wu, W. Zhuang and W.-K. Chen p421
New stability results for 2-D discrete systems based on the Fornasini–Marchesini state space model. A. Kanellakis p427
Overview of SPICE-like circuit simulation algorithms. K.G. Nichols, T.J. Kazmierski, M. Zwolinski and A.D. Brown p242
Pole placement algorithm for equiripple bandstop filter design. J. Teng, J.K. Fidler and L. Zheng p325
Systolic implementation of FIR decimators and interpolators. E. Abdel-Raheem, F. El-Guibaly and A. Antoniou p489
Two-level partitioning algorithm with stable performance. W.-P. Yang, J.-S. Ker, Y.-H. Kuo and Y.-K. Ho p197

METAL-OXIDE-SEMICONDUCTOR STRUCTURES

Computer-aided design of an RF MOSFET power amplifier. G.A. Hoile and H.C. Reader p433
Theoretical and experimental evaluation of high-voltage CMOS inverters. N.D. Janković and E. Bushehri p162

MICROWAVE SYSTEMS

Performance characterisation of a microwave transistor. F. Güneş, M. Güneş and M. Fidan p337

MODULATION

Optimisation of signal phase split in vector modulator phase shifters. R.W. Bernstein and C.F. Heide p207

NETWORKS

Consideration of multiplexing in neural network hardware. M.P. Craven, K.M. Curtis and B.R. Hayes-Gill p237
Neural network for pattern association in electrical capacitance tomography. A.Y. Nooralahiyan, B.S. Hoyle and N.J. Bailey p517
Uniqueness of solutions of networks with two terminal piecewise linear resistors. V.C. Prasad and V.P. Prakash p369

NOISE AND INTERFERENCE

Analysis of a composite amplifier technique for optimum noise performance. A.J. Peyton, Y. Abou-Fakher and B. Wilson p210

NUMERICAL ANALYSIS

Extended harmonic balance method. E. Kleihorst p275

PHASING AND PHASE CONTROL

Fast peak detector for variable frequency three-phase sinusoidal signals. M.-C. Jiang and C.-T. Pan p151

SEMICONDUCTOR DEVICES AND MATERIALS

Analysis of nonlinearities in MOS floating resistor networks. G. Wilson and P.K. Chan p82
Analytical model for the AlGaAs/GaAs multiemitter finger HBT including self-heating and thermal coupling effects. J.J. Liou, L.L. Liou and C.I. Huang p469
Approach to the synthesis of canonic RC-active oscillators using CCII. S. Celma, P.A. Martínez and A. Carlosena p493
Current transistor–transistor–inductor oscillator. J.C. Commerçon and M. Guivarch p498
Degradation in on-state characteristics of IGBTs through self-heating. Z.R. Hu, P.A. Mawby, M.S. Towers, K. Board and J. Zeng p439
Design and operation of poly-Si analogue circuits. C. Reita and S. Fluxman p60
Hot carrier effects in devices and circuits formed from poly-Si. J.R. Ayres and N.D. Young p38
Hot-hole-induced degradation in polycrystalline silicon thin-film transistors: experimental and theoretical analysis. A. Pecora, G. Tallarida, G. Fortunato, L. Mariucci, C. Reita and P. Migliorato p33
In-*situ* phosphorous-doped VLPCVD polysilicon layers for polysilicon thin-film transistors. M. Sarret, A. Liba, O. Bonnaud, F. Le Bihan, B. Fortin, L. Pichon and F. Raoult p19
Large-area shower implanter for thin-film transistors. Y. Wu, J.H. Montgomery, A. Refsum, S.J.N. Mitchell, B.M. Armstrong and H.S. Gamble p23
NMOS and CMOS polysilicon drive circuits for liquid crystal displays. M.J. Edwards p50
Optoelectronic and structural properties of polysilicon produced by excimer laser and furnace crystallisation of hydrogenated amorphous silicon (a-Si:H). T.E. Dyer, J.M. Marshall, W. Pickin, A.R. Hepburn and J.F. Davies p15
Photocurrents in poly-Si TFTs. J.R. Ayres, S.D. Brotherton, I.R. Clarence and P.J. Dobson p27
Recombination and Joule heating effects in GTO thyristors with spatially varying lifetimes. P.A. Mawby, Z.-R. Hu, M.S. Towers, M.J. Evans and K. Board p292

SIGNAL PROCESSING

Clock feedthrough analysis and cancellation in current sample/hold circuits. H.K. Yang and E.I. El-Masry p510
Simple binary to residue transformation with respect to $2^m + 1$ moduli. F. Pourbigharaz and H.M. Yassine p522

SIMULATION

Analytical model for the AlGaAs/GaAs multiemitter finger HBT including self-heating and thermal coupling effects. J.J. Liou, L.L. Liou and C.I. Huang p469
Degradation in on-state characteristics of IGBTs through self-heating. Z.R. Hu, P.A. Mawby, M.S. Towers, K. Board and J. Zeng p439
Improved passive model for transient prediction of GaAs E/D MESFET analogue switches. S. Feng and D. Seitzer p105
Improvement on the diagonal routing model. X. Tan and X. Song p535
Modular SPICE macromodel for operational amplifiers. M.E. Brinson and D.J. Faulkner p417

SOUND BROADCASTING AND AUDIO

Differential-current derived feedback in error-correcting audio amplifier applications. M.O.J. Hawksford p227
Integrated fourth-order $\Sigma\Delta$ convertor with stable self-tuning continuous-time noise shaper. W. Redman-White and A.M. Durham p145

STABILITY

New stability results for 2-D discrete systems based on the Fornasini–Marchesini state space model. A. Kanellakis p427

SWITCHES AND SWITCHING THEORY

Improved passive model for transient prediction of GaAs E/D MESFET analogue switches. S. Feng and D. Seitzer p105
Two-dimensional analysis of GTO switching under the influence of external circuit. M. Turowski and A. Napieralski p483

THYRISTORS

Recombination and Joule heating effects in GTO thyristors with spatially varying lifetimes. P.A. Mawby, Z.-R. Hu, M.S. Towers, M.J. Evans and K. Board p292

TRANSISTORS

Analysis of nonlinearities in MOS floating resistor networks. G. Wilson and P.K. Chan p82
Analytical extraction method for submicron MOS transistor model parameters in the linear region. P.R. Karlsson and K.O. Jeppson p457
Base current reversal in bipolar transistors and circuits: a review and update. J.S. Yuan p299
CMOS triode-transistor transconductor for high-frequency continuous-time filters. U. Gatti, F. Maloberti, G. Palmisano and G. Torelli p462
Current status and future prospects of poly-Si devices. M.G. Clark p3
Design and evaluation of a current-mode multiple-valued PLA based on a resonant tunnelling transistor model. X. Deng, T. Hanyu and M. Kameyama p445
Design and performance of digital polysilicon thin-film-transistor circuits on glass. S.M. Fluxman p56
High-field effects in polysilicon thin-film transistors. M. Quinn, P. Migliorato, C. Reita, A. Pecora, G. Tallarida and G. Fortunato p45
Low-temperature ($\leqslant 600°C$) polysilicon thin-film transistors. R.J. Stroh, F. Plais, T. Kretz, P. Legagneux, O. Huet, M. Magis, D. Pribat, N. Jiang, M.C. Hugon and B. Agius p9
Performance characterisation of a microwave transistor. F. Güneş, M. Güneş and M. Fidan p337
Theoretical and experimental evaluation of high-voltage CMOS inverters. N.D. Janković and E. Bushehri p162

VERY LARGE SCALE INTEGRATION

Explicit formula for harmonic distortion in SC filters with weakly nonlinear capacitors. M.C. Schneider, C. Galup-Montoro and J.C.M. Bermudez p505
Fast VLSI architectures using nonredundant multibit recoding for computing A^Y mod N. B.S. Prasanna and P.V. Ananda Mohan p345
Improvement on the diagonal routing model. X. Tan and X. Song p535

X-RAYS

Effect of X-ray irradiation on submicrometre channel length MOSFETs. P.K. Bhattacharya and R.P. Nandakumar p193